

**2N6249 – 2N6250 – 2N6251**

**HIGH VOLTAGE NPN SILICON POWER TRANSISTORS**

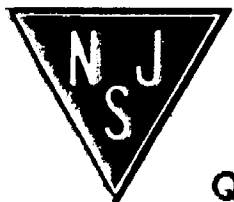
The 2N6249 – 2N6250 – 2N6251 are NPN silicon transistors in Jedec TO-3. They are designed for high voltage inverters, switching regulators and line operated amplifier applications. Especially well suited for switching power supply applications.

- High Voltage Breakdown Rating
- Low Saturation Voltages
- Fast Switching Capability
- High  $E_{s/b}$  Energy Handling Capability

**ABSOLUTE MAXIMUM RATINGS**

Symbol	Ratings		Value	Unit			
$V_{CEO}$	#Collector-Emitter Voltage (1)		200	V			
			275				
			350				
$V_{CER}$	#Collector-Emitter Voltage (1)	$R_{BE}=50\Omega$	225	V			
			300				
			375				
$V_{CB}$	Collector-Base Voltage (1)		300	Vdc			
			375				
			450				
$V_{EB}$	Emitter-Base Voltage		6.0	Vdc			
$I_C$	Collector Current	Continuous (1)	15	Adc			
			Peak		30		
		$I_B$	Base Current		Continuous (1)	10	Adc
						Peak	
$I_E$	Emitter Current			Continuous	25	Adc	
					Peak		

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## 2N6249 – 2N6250 – 2N6251

$P_t$	Total Power Dissipation	@ $T_C = 25^\circ$	2N6249 2N6250 2N6251	175	Watts
		@ $T_C = 100^\circ$	2N6249 2N6250 2N6251	100	
		Derate above $25^\circ$ (1)	2N6249 2N6250 2N6251	1.0	W/°C
$T_J$	Junction Temperature (1)		2N6249 2N6250 2N6251	-65 to +200	°C
$T_{stg}$	Storage Temperature (1)		2N6249 2N6250 2N6251	-65 to +200	°C

(1) This data guaranteed in addition to JEDEC registered data.

### THERMAL CHARACTERISTICS

Symbol	Ratings	Value	Unit
$R_{thJC}$	Thermal Resistance, Junction to Case	2N6249 2N6250 2N6251	1 °C/W
$T_L$	Maximum Lead Temperature for Soldering Purposes : 1/8" from Case for 5 Secondes	2N6249 2N6250 2N6251	275 °C

### ELECTRICAL CHARACTERISTICS

$T_C=25^\circ\text{C}$  unless otherwise noted

Symbol	Ratings	Test Condition(s)	Min	Typ	Mx	Unit	
$V_{CEO(SUS)}$	Collector-Emitter Sustaining Voltage	$I_C=200\text{ mAdc}, I_B=0$	2N6249	200	-	-	Vdc
			2N6250	275	-	-	
			2N6251	350	-	-	
$V_{CER(SUS)}$	Collector-Emitter Sustaining Voltage	$I_C=0.2\text{ Adc}, R_{BE}=50\Omega$	2N6249	225	-	-	V
			2N6250	300	-	-	
			2N6251	375	-	-	
$I_{CEO}$	Collector-Emitter Current	$V_{CE}=150\text{ Vdc}, I_B=0$	2N6249	-	-	5.0	mAdc
		$V_{CE}=225\text{ Vdc}, I_B=0$	2N6250	-	-	5.0	
		$V_{CE}=300\text{ Vdc}, I_B=0$	2N6251	-	-	5.0	
$I_{CEX}$	Collector Cutoff Current	$V_{CE}=225\text{ Vdc}, V_{EB(off)}=1.5\text{ Vdc}$	2N6249	-	-	5.0	mAdc
		$V_{CE}=225\text{ Vdc}, V_{EB(off)}=1.5\text{ Vdc}, T_C = 150^\circ\text{C}$		-	-	10	
		$V_{CE}=300\text{ Vdc}, V_{EB(off)}=1.5\text{ Vdc}$	2N6250	-	-	5.0	
		$V_{CE}=300\text{ Vdc}, V_{EB(off)}=1.5\text{ Vdc}, T_C = 150^\circ\text{C}$		-	-	10	
		$V_{CE}=375\text{ Vdc}, V_{EB(off)}=1.5\text{ Vdc}$	2N6251	-	-	5.0	
		$V_{CE}=375\text{ Vdc}, V_{EB(off)}=1.5\text{ Vdc}, T_C = 150^\circ\text{C}$		-	-	10	

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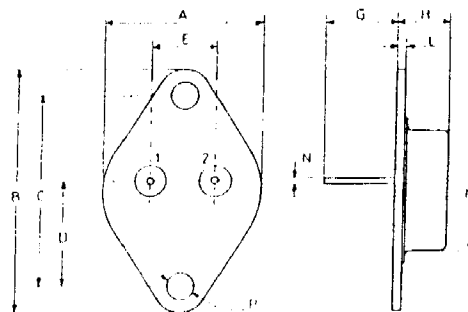
$I_{EBO}$	Emitter Cutoff Current	$V_{BE}=6.0$ Vdc, $I_C=0$	2N6249 2N6250 2N6251	-	-	1.0	mAdc
$I_{s/b}$	Second Breakdown Collector Current with base forward biased $t=1.0$ S non-repetitive	$V_{CE}=30$ Vdc	2N6249	5.8	-	-	Vdc
			2N6250	5.8	-	-	
			2N6251	5.8	-	-	
$E_{s/b}$	Second Breakdown Energy with base reverse biased $t=1.0$ S non-repetitive	$I_C=10$ A, $V_{BE(off)}=4.0$ Vdc, $L=50$ $\mu$ H	2N6249	2.5	-	-	mJ
			2N6250	2.5	-	-	
			2N6251	2.5	-	-	
$h_{FE}$	DC Current Gain	$I_C=10$ Adc, $V_{CE}=3.0$ Vdc	2N6249	10	-	50	-
			2N6250	8.0	-	50	
			2N6251	6.0	-	50	
$V_{CE(SAT)}$	Collector-Emitter saturation Voltage (1)	$I_C=10$ Adc, $I_B=1$ Adc	2N6249	-	-	1.5	Vdc
		$I_C=10$ Adc, $I_B=1.25$ Adc	2N6250	-	-	1.5	
		$I_C=10$ Adc, $I_B=1.67$ Adc	2N6251	-	-	1.5	
$V_{BE(SAT)}$	Base-Emitter saturation Voltage (1)	$I_C=10$ Adc, $I_B=1$ Adc	2N6249	-	-	2.5	Vdc
		$I_C=10$ Adc, $I_B=1.25$ Adc	2N6250	-	-	2.5	
		$I_C=10$ Adc, $I_B=1.67$ Adc	2N6251	-	-	2.5	

(1) Measured on a curve tracer (60 Hz full-wave rectified sine wave ).

Symbol	Ratings	Test Condition(s)	Min	Typ	Mx	Unit
$f_T$	Current Gain – Bandwidth Product	$V_{CE}=10$ Vdc, $I_C=1.0$ Adc, $f_{test}=1.0$ Mhz	2.5	-	-	MHz
$t_r$	Rise Time	$V_{CC}=200$ Vdc, $I_C=10$ A, Duty Cycle $\leq 2.0\%$ $t_p=100$ $\mu$ s $I_{B1}=I_{B2}=1.0$ Adc	-	-	2.0	$\mu$ s
$t_s$	Storage Time	$I_{B1}=I_{B2}=1.25$ Adc	-	-	3.5	
$t_f$	Fall Time	$I_{B1}=I_{B2}=1.67$ Adc	-	-	1.0	

### MECHANICAL DATA CASE TO-3

DIMENSIONS		
	mm	inches
A	25,51	1,004
B	38,93	1,53
C	30,12	1,18
D	17,25	0,68
E	10,89	0,43
G	11,62	0,46
H	8,54	0,34
L	1,55	0,6
M	19,47	0,77
N	1	0,04
P	4,06	0,16



Pin 1 :	Base
Pin 2 :	Emitter
Case :	Collector